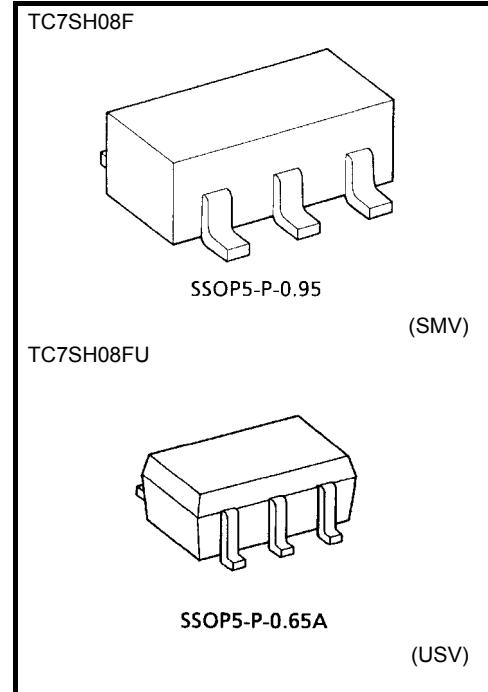
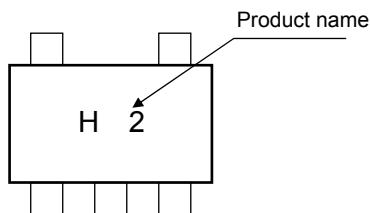


TC7SH08F, TC7SH08FU

Features

- High speed operation : $t_{pd} = 4.3\text{ns}$ (typ.) at $V_{CC} = 5\text{V}$, 15pF
- Low power dissipation : $I_{CC} = 2 \mu\text{A}$ (max) at $T_a = 25^\circ\text{C}$
- High noise immunity : $V_{NIH} = V_{NIL} = 28\%$ V_{CC} (min)
- 5.5-V tolerant inputs
- Wide operating voltage range : $V_{CC} = 2$ to 5.5V

Marking



Weight
 SSOP5-P-0.95 : 0.016 g (typ.)
 SSOP5-P-0.65A : 0.006 g (typ.)

Absolute Maximum Ratings ($T_a = 25^\circ\text{C}$)

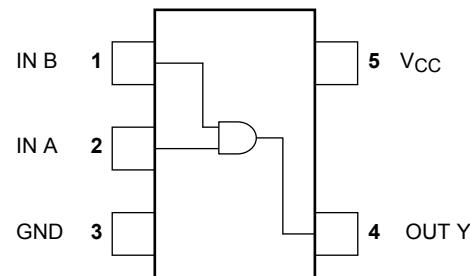
Characteristics	Symbol	Rating	Unit
Supply voltage	V_{CC}	- 0.5 to 7	V
DC input voltage	V_{IN}	- 0.5 to 7	V
DC output voltage	V_{OUT}	- 0.5 to $V_{CC} + 0.5$	V
Input diode current	I_{IK}	- 20	mA
Output diode current	I_{OK}	± 20 (Note1)	mA
DC output current	I_{OUT}	± 25	mA
DC V_{CC} /ground current	I_{CC}	± 50	mA
Power dissipation	P_D	200	mW
Storage temperature	T_{STG}	- 65 to 150	°C
Lead temperature (10 s)	T_L	260	°C

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the TY Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc.).

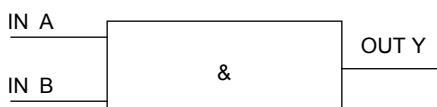
Note1: $V_{OUT} < GND$, $V_{OUT} > V_{CC}$

Pin Assignment (top view)



TC7SH08F, TC7SH08FU

IEC Logic Symbol



Truth Table

A	B	Y
L	L	L
L	H	L
H	L	L
H	H	H

Operating Ranges

Characteristics	Symbol	Rating	Unit
Supply voltage	V _{CC}	2.0 to 5.5	V
Input voltage	V _{IN}	0 to 5.5	V
Output voltage	V _{OUT}	0 to V _{CC}	V
Operating temperature	T _{opr}	-40 to 85	°C
Input rise and fall time	dt/dv	0 to 100 (V _{CC} = 3.3±0.3V)	ns/V
		0 to 20 (V _{CC} = 5.0±0.5V)	

TC7SH08F, TC7SH08FU

Electrical Characteristics

DC Characteristics

Characteristics	Symbol	Test Condition	V _{CC} (V)	Ta = 25°C			Ta = -40 to 85°C		Unit	
				Min	Typ.	Max	Min	Max		
High-level input voltage	V _{IH}	—	2.0	1.5	—	—	1.5	—	V	
			3.0 to 5.5	V _{CC} × 0.7	—	—	V _{CC} × 0.7	—		
Low-level input voltage	V _{IL}	—	2.0	—	—	0.5	—	0.5	V	
			3.0 to 5.5	—	—	V _{CC} × 0.3	—	V _{CC} × 0.3		
High-level output voltage	V _{OH}	V _{IN} = V _{IH}	I _{OH} = -50 µA	2.0	1.9	2.0	—	1.9	—	V
				3.0	2.9	3.0	—	2.9	—	
				4.5	4.4	4.5	—	4.4	—	
			I _{OH} = -4 mA	3.0	2.58	—	—	2.48	—	
			I _{OH} = -8 mA	4.5	3.94	—	—	3.80	—	
Low-level output voltage	V _{OL}	V _{IN} = V _{IH} or V _{IL}	I _{OL} = 50 µA	2.0	—	0	0.10	—	0.10	V
				3.0	—	0	0.10	—	0.10	
				4.5	—	0	0.10	—	0.10	
			I _{OL} = 4mA	3.0	—	—	0.36	—	0.44	
			I _{OL} = 8 mA	4.5	—	—	0.36	—	0.44	
Input leakage current	I _{IN}	V _{IN} = 5.5 V or GND	0 to 5.5	—	—	±0.1	—	±1.0	µA	
Quiescent supply current	I _{CC}	V _{IN} = V _{CC} or GND	5.5	—	—	2.0	—	20.0	µA	

TC7SH08F, TC7SH08FU

AC Characteristics (unless otherwise specified, Input: $t_r = t_f = 3 \text{ ns}$)

Characteristics	Symbol	Test Condition		Ta = 25°C			Ta = -40 to 85°C		Unit
		V _{CC} (V)	C _L (pF)	Min	Typ.	Max	Min	Max	
Propagation delay time	t _{PLH}	3.3 ± 0.3	15	—	6.2	8.8	1.0	10.5	ns
			50	—	8.7	12.3	1.0	14.0	
	t _{PHL}	5.0 ± 0.5	15	—	4.3	5.9	1.0	7.0	
			50	—	5.8	7.9	1.0	9.0	
Input capacitance	C _{IN}	—			—	4	10	—	10 pF
Power dissipation capacitance	C _{PD}	(Note 2)			—	14	—	—	— pF

Note 2: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

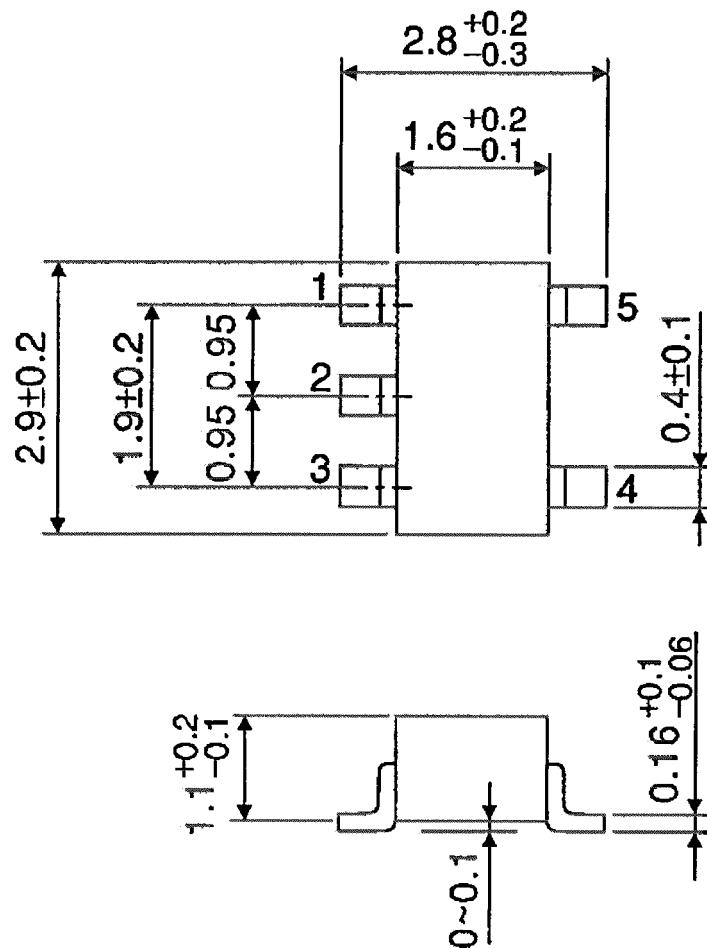
$$I_{CC} (\text{opr.}) = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$$

TC7SH08F, TC7SH08FU

Package Dimensions

SSOP5-P-0.95

Unit : mm



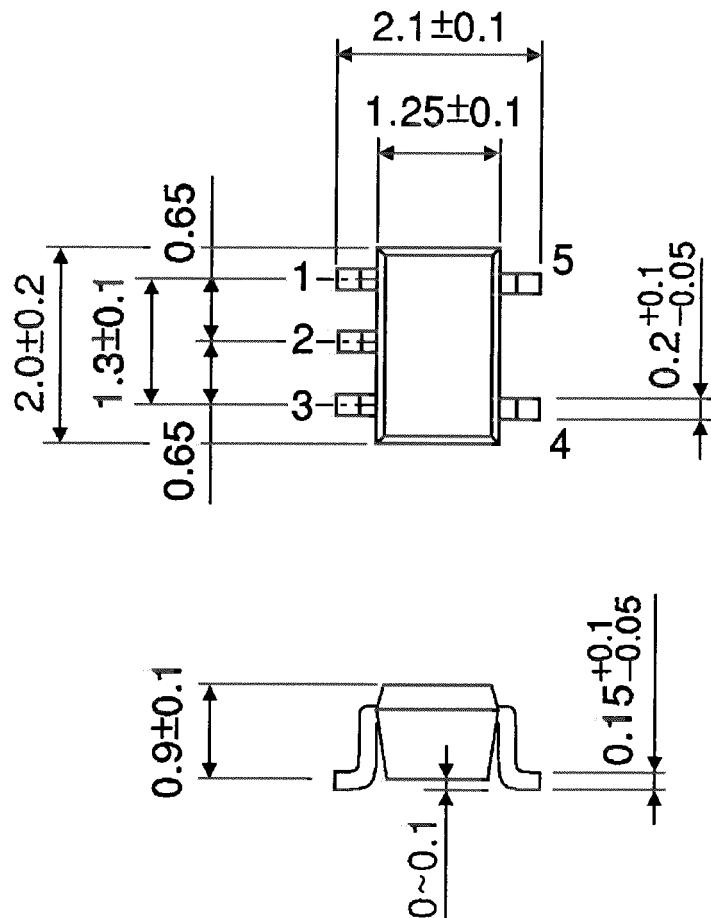
Weight: 0.016 g (typ.)

TC7SH08F, TC7SH08FU

Package Dimensions

SSOP5-P-0.65A

Unit : mm



Weight: 0.006 g (typ.)